



1N4001GP - 1N4007GP

Features

- Low forward voltage drop.
- High surge current capability.
- High reliability.
- High current capability.



General Purpose Rectifiers (Glass Passivated)

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value							Units
		4001GP	4002GP	4003G	4004GP	4005GP	4006GP	4007GP	
V_{RRM}	Maximum Repetitive Reverse Voltage	50	100	200	400	600	800	1000	V
$I_{F(AV)}$	Average Rectified Forward Current, .375 " lead length @ $T_A = 75^\circ\text{C}$				1.0				A
I_{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave				30				A
T_{stg}	Storage Temperature Range				-65 to +175				$^\circ\text{C}$
T_J	Operating Junction Temperature				-65 to +175				$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value							Units
P_D	Power Dissipation				3.0				W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient				50				$^\circ\text{C}/\text{W}$

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Device							Units
		4001GP	4002GP	4003G	4004GP	4005GP	4006GP	4007GP	
V_F	Forward Voltage @ 1.0 A				1.1				V
I_R	Reverse Current @ rated V_R $T_A = 25^\circ\text{C}$ $T_A = 125^\circ\text{C}$				5.0				μA
C_T	Total Capacitance $V_R = 4.0 \text{ V}, f = 1.0 \text{ MHz}$				50				μA
					8.0				pF

General Purpose Rectifiers (Glass Passivated)

(continued)

Typical Characteristics

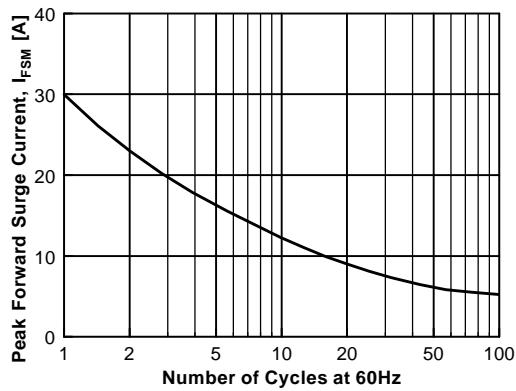


Figure 1. Non-Repetitive Surge Current

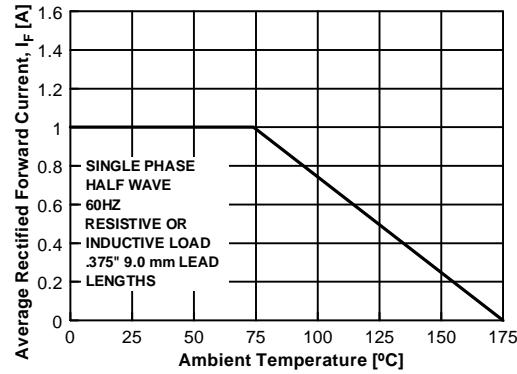


Figure 2. Forward Current Derating Curve

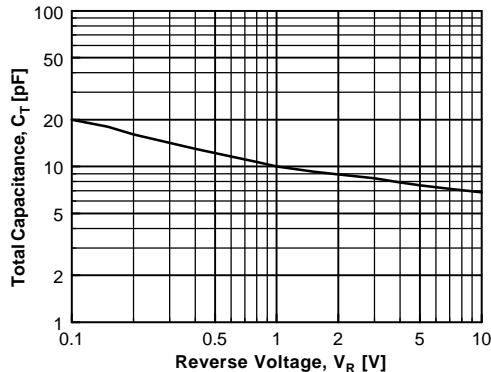


Figure 3. Total Capacitance

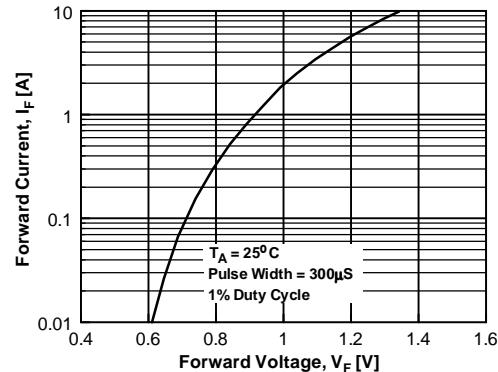


Figure 4. Forward Voltage Characteristics